# NSN 5961-01-080-1889

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#### **Inclosure Material:**

Metal

**Overall Length:** 

1.553 inches

# **Overall Height:**

0.380 inches

# **Overall Width:**

1.050 inches

#### **Overall Diameter:**

0.875 inches

# Mounting Facility Quantity:

2

#### Internal Configuration:

Junction contact

Electrode Internally-electrically Connected To Case:

Collector

#### Mounting Method:

Unthreaded hole

# **Features Provided:**

Hermetically sealed case

# Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

150.0 collector to base voltage/static/emitter open and 90.0 collector to emitter voltage/static/base open and 7.0 emitter to base voltage,

static, collector open

# **Current Rating Per Characteristic:**

Between 5.00 amperes source cutoff current and 20.00 amperes source cutoff current

# **Power Rating Per Characteristic:**

140.0 watts small-signal input power, common-collector preset

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

#### **Special Features:**

Junction pattern arrangement: npn

#### **Test Data Document:**

06509-122024 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

#### **Terminal Type And Quantity:**

1 case and 2 pin

Shelf Life:

N/a

#### Unit Of Measure:

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Demilitarization:

No

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